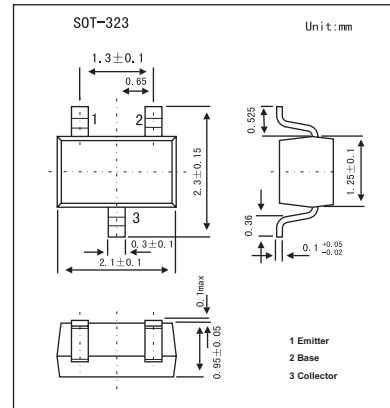


■ Features

- Good linearity of fr.



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V _{CB0}	30	V
Collector-emitter voltage	V _{CEO}	25	V
Emitter-base voltage	V _{EBO}	4	V
Collector current	I _C	50	mA
Base current	I _B	25	mA
Collector power dissipation	P _C	100	mW
Junction temperature	T _J	125	°C
Storage temperature	T _{stg}	-55 to +125	°C

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector cut-off current	I _{CB0}	V _{CB} = 30 V, I _E = 0			0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = 3 V, I _C = 0			0.1	μA
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C = 1 mA, I _B = 0	25			V
DC current gain	h _{FE}	V _{CE} = 10 V, I _C = 10 mA	20	70	200	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 15 mA, I _B = 1.5mA			0.2	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C = 15 mA, I _B = 1.5mA			1.5	V
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1MHz		1.1	1.6	pF
Collector-base time constant	C _{c.rbb'}	V _{CB} = 10 V, I _C = 1mA, f = 30MHz			25	ps
Transition frequency	f _T	V _{CE} = 10 V, I _C = 10 mA	250	600		MHz

■ Marking

Marking	HH
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